

L Number	Hits	Search Text	DB	Time stamp
1	2853607	memory or storage	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 09:49
2	3463	(memory or storage) and (voltage or potential or level) with waveform with (cell or unit)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:00
3	73	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with noise	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:02
4	73	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 09:53
6	1	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)) and (stimulus or var\$6 with time) with (noise or disturb\$5) with reduc\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:02
7	3	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)) and (stimulus or sin\$7 or trianl\$5) with (noise or disturb\$5) with reduc\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 09:59
8	3	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)) and (stimulus or sin\$7 or trianl\$5) with (noise or disturb\$5) with reduc\$5) and read\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 09:59
9	30469	(memory or storage) and (voltage or potential or level) with (cell or unit) with read\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:01
10	209	((memory or storage) and (voltage or potential or level) with (cell or unit) with read\$5) and (current or voltage ot frequency or time) with measur\$5 with noise	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:02
11	4	((memory or storage) and (voltage or potential or level) with (cell or unit) with read\$5) and (current or voltage ot frequency or time) with measur\$5 with noise) and (stimulus or var\$6 with time) with (noise or disturb\$5) with reduc\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:04
12	34967	(memory or storage) and sense adj amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:05
13	1	((memory or storage) and sense adj amplifier) and (episodic adj stimulus)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:06
14	47	((memory or storage) and sense adj amplifier) and var\$5 with time with (voltage or potential or level) with sense near3 (voltage or potential or level)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:08

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2	3463	(memory or storage) and (voltage or potential or level) with waveform with (cell or unit)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:00
3	73	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with noise	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:02
4	73	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 09:53
6	1	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)) and (stimulus or var\$6 with time) with (noise or distrub\$5) with reduc\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:02
7	3	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)) and (stimulus or sin\$7 or trianl\$5) with (noise or distrub\$5) with reduc\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 09:59
8	3	((memory or storage) and (voltage or potential or level) with waveform with (cell or unit)) and (current or voltage ot frequency or time) with measur\$5 with (noise or distrub\$5)) and (stimulus or sin\$7 or trianl\$5) with (noise or distrub\$5) with reduc\$5 and read\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 09:59
9	30469	(memory or storage) and (voltage or potential or level) with (cell or unit) with read\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:01
10	209	((memory or storage) and (voltage or potential or level) with (cell or unit) with read\$5) and (current or voltage ot frequency or time) with measur\$5 with noise	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:02
11	4	((memory or storage) and (voltage or potential or level) with (cell or unit) with read\$5) and (current or voltage ot frequency or time) with measur\$5 with noise) and (stimulus or var\$6 with time) with (noise or distrub\$5) with reduc\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:04
12	34967	(memory or storage) and sense adj amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:05
13	1	((memory or storage) and sense adj amplifier) and (episodic adj stimulus)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:06
14	47	((memory or storage) and sense adj amplifier) and var\$5 with time with (voltage or potential or level) with sense near3 (voltage or potential or level)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/21 10:08